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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

|                            |                                                                                                                                                             |
|----------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Product Status             | Active                                                                                                                                                      |
| Core Processor             | ARM® Cortex®-M4                                                                                                                                             |
| Core Size                  | 32-Bit Single-Core                                                                                                                                          |
| Speed                      | 100MHz                                                                                                                                                      |
| Connectivity               | EBI/EMI, Ethernet, I <sup>2</sup> C, IrDA, SD, SPI, UART/USART, USB, USB OTG                                                                                |
| Peripherals                | DMA, I <sup>2</sup> S, LCD, LVD, POR, PWM, WDT                                                                                                              |
| Number of I/O              | 94                                                                                                                                                          |
| Program Memory Size        | 512KB (512K x 8)                                                                                                                                            |
| Program Memory Type        | FLASH                                                                                                                                                       |
| EEPROM Size                | -                                                                                                                                                           |
| RAM Size                   | 128K x 8                                                                                                                                                    |
| Voltage - Supply (Vcc/Vdd) | 1.71V ~ 3.6V                                                                                                                                                |
| Data Converters            | A/D 41x16b; D/A 2x12b                                                                                                                                       |
| Oscillator Type            | Internal                                                                                                                                                    |
| Operating Temperature      | -40°C ~ 85°C (TA)                                                                                                                                           |
| Mounting Type              | Surface Mount                                                                                                                                               |
| Package / Case             | 144-LBGA                                                                                                                                                    |
| Supplier Device Package    | 144-MAPBGA (13x13)                                                                                                                                          |
| Purchase URL               | <a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mk53dn512cmd10">https://www.e-xfl.com/product-detail/nxp-semiconductors/mk53dn512cmd10</a> |

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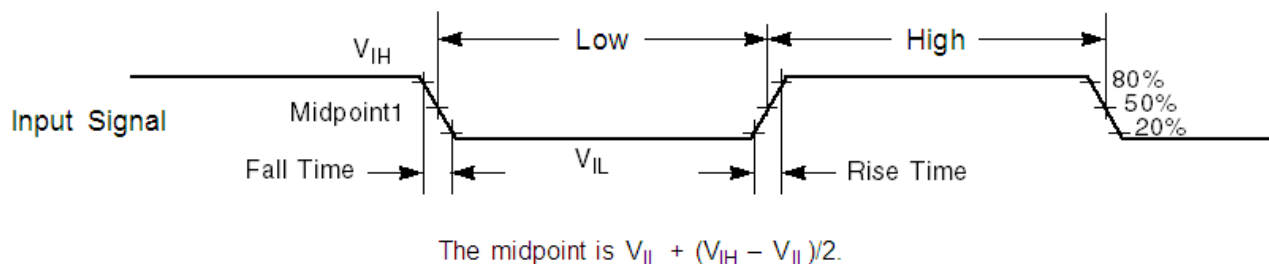
| Symbol        | Description                                                    | Min.           | Max.           | Unit |
|---------------|----------------------------------------------------------------|----------------|----------------|------|
| $V_{DD}$      | Digital supply voltage                                         | -0.3           | 3.8            | V    |
| $I_{DD}$      | Digital supply current                                         | —              | 185            | mA   |
| $V_{DIO}$     | Digital input voltage (except RESET, EXTAL, and XTAL)          | -0.3           | 5.5            | V    |
| $V_{AIO}$     | Analog <sup>1</sup> , RESET, EXTAL, and XTAL input voltage     | -0.3           | $V_{DD} + 0.3$ | V    |
| $I_D$         | Maximum current single pin limit (applies to all digital pins) | -25            | 25             | mA   |
| $V_{DDA}$     | Analog supply voltage                                          | $V_{DD} - 0.3$ | $V_{DD} + 0.3$ | V    |
| $V_{USB\_DP}$ | USB_DP input voltage                                           | -0.3           | 3.63           | V    |
| $V_{USB\_DM}$ | USB_DM input voltage                                           | -0.3           | 3.63           | V    |
| VREGIN        | USB regulator input                                            | -0.3           | 6.0            | V    |
| $V_{BAT}$     | RTC battery supply voltage                                     | -0.3           | 3.8            | V    |

1. Analog pins are defined as pins that do not have an associated general purpose I/O port function.

## 5 General

### 5.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



**Figure 1. Input signal measurement reference**

All digital I/O switching characteristics assume:

1. output pins
  - have  $C_L=30\text{pF}$  loads,
  - are configured for fast slew rate ( $\text{PORTx\_PCRn[SRE]}=0$ ), and
  - are configured for high drive strength ( $\text{PORTx\_PCRn[DSE]}=1$ )
2. input pins
  - have their passive filter disabled ( $\text{PORTx\_PCRn[PFE]}=0$ )

**Table 6. Power consumption operating behaviors (continued)**

| Symbol                | Description                                                                | Min. | Typ. | Max. | Unit | Notes |
|-----------------------|----------------------------------------------------------------------------|------|------|------|------|-------|
| I <sub>DD_VLPR</sub>  | Very-low-power run mode current at 3.0 V — all peripheral clocks enabled   | —    | 1.71 | —    | mA   | 7     |
| I <sub>DD_VLPW</sub>  | Very-low-power wait mode current at 3.0 V — all peripheral clocks disabled | —    | 0.77 | —    | mA   | 8     |
| I <sub>DD_STOP</sub>  | Stop mode current at 3.0 V                                                 |      |      |      |      |       |
|                       | • @ –40 to 25°C                                                            | —    | 0.74 | 1.41 | mA   |       |
|                       | • @ 70°C                                                                   | —    | 2.45 | 11.5 | mA   |       |
|                       | • @ 105°C                                                                  | —    | 6.61 | 30   | mA   |       |
| I <sub>DD_VLPS</sub>  | Very-low-power stop mode current at 3.0 V                                  |      |      |      |      |       |
|                       | • @ –40 to 25°C                                                            | —    | 83   | 435  | μA   |       |
|                       | • @ 70°C                                                                   | —    | 425  | 2000 | μA   |       |
|                       | • @ 105°C                                                                  | —    | 1280 | 4000 | μA   |       |
| I <sub>DD_LLS</sub>   | Low leakage stop mode current at 3.0 V                                     |      |      |      |      | 9     |
|                       | • @ –40 to 25°C                                                            | —    | 4.58 | 19.9 | μA   |       |
|                       | • @ 70°C                                                                   | —    | 30.6 | 105  | μA   |       |
|                       | • @ 105°C                                                                  | —    | 137  | 500  | μA   |       |
| I <sub>DD_VLLS3</sub> | Very low-leakage stop mode 3 current at 3.0 V                              |      |      |      |      | 9     |
|                       | • @ –40 to 25°C                                                            | —    | 3.0  | 23   | μA   |       |
|                       | • @ 70°C                                                                   | —    | 18.6 | 43   | μA   |       |
|                       | • @ 105°C                                                                  | —    | 84.9 | 230  | μA   |       |
| I <sub>DD_VLLS2</sub> | Very low-leakage stop mode 2 current at 3.0 V                              |      |      |      |      |       |
|                       | • @ –40 to 25°C                                                            | —    | 2.2  | 5.4  | μA   |       |
|                       | • @ 70°C                                                                   | —    | 9.3  | 35   | μA   |       |
|                       | • @ 105°C                                                                  | —    | 41.4 | 128  | μA   |       |
| I <sub>DD_VLLS1</sub> | Very low-leakage stop mode 1 current at 3.0 V                              |      |      |      |      |       |
|                       | • @ –40 to 25°C                                                            | —    | 2.1  | 9    | μA   |       |
|                       | • @ 70°C                                                                   | —    | 7.6  | 28   | μA   |       |
|                       | • @ 105°C                                                                  | —    | 33.5 | 95.5 | μA   |       |
| I <sub>DD_VBAT</sub>  | Average current with RTC and 32kHz disabled at 3.0 V                       |      |      |      |      |       |
|                       | • @ –40 to 25°C                                                            | —    | 0.19 | 0.22 | μA   |       |
|                       | • @ 70°C                                                                   | —    | 0.49 | 0.64 | μA   |       |
|                       | • @ 105°C                                                                  | —    | 2.2  | 3.2  | μA   |       |

Table continues on the next page...

**Table 10. General switching specifications (continued)**

| Symbol | Description                                  | Min. | Max. | Unit | Notes |
|--------|----------------------------------------------|------|------|------|-------|
|        | Port rise and fall time (low drive strength) |      |      |      | 5     |
|        | • Slew disabled                              |      |      |      |       |
|        | • $1.71 \leq V_{DD} \leq 2.7V$               | —    | 12   | ns   |       |
|        | • $2.7 \leq V_{DD} \leq 3.6V$                | —    | 6    | ns   |       |
|        | • Slew enabled                               |      |      |      |       |
|        | • $1.71 \leq V_{DD} \leq 2.7V$               | —    | 36   | ns   |       |
|        | • $2.7 \leq V_{DD} \leq 3.6V$                | —    | 24   | ns   |       |

1. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In Stop, VLPS, LLS, and VLLSx modes, the synchronizer is bypassed so shorter pulses can be recognized in that case.
2. The greater synchronous and asynchronous timing must be met.
3. This is the minimum pulse width that is guaranteed to be recognized as a pin interrupt request in Stop, VLPS, LLS, and VLLSx modes.
4. 75 pF load
5. 15 pF load

## 5.4 Thermal specifications

### 5.4.1 Thermal operating requirements

**Table 11. Thermal operating requirements**

| Symbol | Description              | Min. | Max. | Unit |
|--------|--------------------------|------|------|------|
| $T_J$  | Die junction temperature | −40  | 125  | °C   |
| $T_A$  | Ambient temperature      | −40  | 85   | °C   |

### 5.4.2 Thermal attributes

| Board type        | Symbol          | Description                                                  | 144 LQFP | 144 MAPBGA | Unit | Notes |
|-------------------|-----------------|--------------------------------------------------------------|----------|------------|------|-------|
| Single-layer (1s) | $R_{\theta JA}$ | Thermal resistance, junction to ambient (natural convection) | 45       | 48         | °C/W | 1     |

Table continues on the next page...

## Peripheral operating requirements and behaviors

| Board type        | Symbol           | Description                                                                                     | 144 LQFP | 144 MAPBGA | Unit | Notes |
|-------------------|------------------|-------------------------------------------------------------------------------------------------|----------|------------|------|-------|
| Four-layer (2s2p) | $R_{\theta JA}$  | Thermal resistance, junction to ambient (natural convection)                                    | 36       | 29         | °C/W | 1     |
| Single-layer (1s) | $R_{\theta JMA}$ | Thermal resistance, junction to ambient (200 ft./min. air speed)                                | 36       | 38         | °C/W | 1     |
| Four-layer (2s2p) | $R_{\theta JMA}$ | Thermal resistance, junction to ambient (200 ft./min. air speed)                                | 30       | 25         | °C/W | 1     |
| —                 | $R_{\theta JB}$  | Thermal resistance, junction to board                                                           | 24       | 16         | °C/W | 2     |
| —                 | $R_{\theta JC}$  | Thermal resistance, junction to case                                                            | 9        | 9          | °C/W | 3     |
| —                 | $\Psi_{JT}$      | Thermal characterization parameter, junction to package top outside center (natural convection) | 2        | 2          | °C/W | 4     |

1. Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air)*, or EIA/JEDEC Standard JESD51-6, *Integrated Circuit Thermal Test Method Environmental Conditions—Forced Convection (Moving Air)*.
2. Determined according to JEDEC Standard JESD51-8, *Integrated Circuit Thermal Test Method Environmental Conditions—Junction-to-Board*.
3. Determined according to Method 1012.1 of MIL-STD 883, *Test Method Standard, Microcircuits*, with the cold plate temperature used for the case temperature. The value includes the thermal resistance of the interface material between the top of the package and the cold plate.
4. Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air)*.

## 6 Peripheral operating requirements and behaviors

### 6.1 Core modules

**Table 15. MCG specifications (continued)**

| Symbol             | Description                                                                                                                                                                                         | Min.       | Typ. | Max.                                        | Unit          | Notes |
|--------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|------|---------------------------------------------|---------------|-------|
| $J_{cyc\_fll}$     | FLL period jitter <ul style="list-style-type: none"> <li><math>f_{DCO} = 48 \text{ MHz}</math></li> <li><math>f_{DCO} = 98 \text{ MHz}</math></li> </ul>                                            | —          | 180  | —                                           | ps            |       |
| $t_{fll\_acquire}$ | FLL target frequency acquisition time                                                                                                                                                               | —          | —    | 1                                           | ms            | 6     |
| PLL                |                                                                                                                                                                                                     |            |      |                                             |               |       |
| $f_{vco}$          | VCO operating frequency                                                                                                                                                                             | 48.0       | —    | 100                                         | MHz           |       |
| $I_{pll}$          | PLL operating current <ul style="list-style-type: none"> <li>PLL @ 96 MHz (<math>f_{osc\_hi\_1} = 8 \text{ MHz}</math>, <math>f_{pll\_ref} = 2 \text{ MHz}</math>, VDIV multiplier = 48)</li> </ul> | —          | 1060 | —                                           | $\mu\text{A}$ | 7     |
| $I_{pll}$          | PLL operating current <ul style="list-style-type: none"> <li>PLL @ 48 MHz (<math>f_{osc\_hi\_1} = 8 \text{ MHz}</math>, <math>f_{pll\_ref} = 2 \text{ MHz}</math>, VDIV multiplier = 24)</li> </ul> | —          | 600  | —                                           | $\mu\text{A}$ | 7     |
| $f_{pll\_ref}$     | PLL reference frequency range                                                                                                                                                                       | 2.0        | —    | 4.0                                         | MHz           |       |
| $J_{cyc\_pll}$     | PLL period jitter (RMS) <ul style="list-style-type: none"> <li><math>f_{vco} = 48 \text{ MHz}</math></li> <li><math>f_{vco} = 100 \text{ MHz}</math></li> </ul>                                     | —          | 120  | —                                           | ps            | 8     |
| $J_{acc\_pll}$     | PLL accumulated jitter over 1 $\mu\text{s}$ (RMS) <ul style="list-style-type: none"> <li><math>f_{vco} = 48 \text{ MHz}</math></li> <li><math>f_{vco} = 100 \text{ MHz}</math></li> </ul>           | —          | 1350 | —                                           | ps            | 8     |
| $D_{lock}$         | Lock entry frequency tolerance                                                                                                                                                                      | $\pm 1.49$ | —    | $\pm 2.98$                                  | %             |       |
| $D_{unl}$          | Lock exit frequency tolerance                                                                                                                                                                       | $\pm 4.47$ | —    | $\pm 5.97$                                  | %             |       |
| $t_{pll\_lock}$    | Lock detector detection time                                                                                                                                                                        | —          | —    | $150 \times 10^{-6} + 1075(1/f_{pll\_ref})$ | s             | 9     |

1. This parameter is measured with the internal reference (slow clock) being used as a reference to the FLL (FEI clock mode).
2. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=0.
3. The resulting system clock frequencies should not exceed their maximum specified values. The DCO frequency deviation ( $\Delta f_{dco\_t}$ ) over voltage and temperature should be considered.
4. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=1.
5. The resulting clock frequency must not exceed the maximum specified clock frequency of the device.
6. This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
7. Excludes any oscillator currents that are also consuming power while PLL is in operation.
8. This specification was obtained using a Freescale developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary.
9. This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

## 6.3.2 Oscillator electrical specifications

This section provides the electrical characteristics of the module.



**Table 21. Flash command timing specifications (continued)**

| Symbol                                         | Description                                                        | Min. | Typ. | Max. | Unit          | Notes |
|------------------------------------------------|--------------------------------------------------------------------|------|------|------|---------------|-------|
| $t_{\text{swapx01}}$                           | Swap Control execution time<br>• control code 0x01                 | —    | 200  | —    | $\mu\text{s}$ |       |
| $t_{\text{swapx02}}$                           | • control code 0x02                                                | —    | 70   | 150  | $\mu\text{s}$ |       |
| $t_{\text{swapx04}}$                           | • control code 0x04                                                | —    | 70   | 150  | $\mu\text{s}$ |       |
| $t_{\text{swapx08}}$                           | • control code 0x08                                                | —    | —    | 30   | $\mu\text{s}$ |       |
| $t_{\text{pgmpart64k}}$                        | Program Partition for EEPROM execution time<br>• 64 KB FlexNVM     | —    | 138  | —    | ms            |       |
| $t_{\text{pgmpart256k}}$                       | • 256 KB FlexNVM                                                   | —    | 145  | —    | ms            |       |
| $t_{\text{setramff}}$                          | Set FlexRAM Function execution time:<br>• Control Code 0xFF        | —    | 70   | —    | $\mu\text{s}$ |       |
| $t_{\text{setram32k}}$                         | • 32 KB EEPROM backup                                              | —    | 0.8  | 1.2  | ms            |       |
| $t_{\text{setram64k}}$                         | • 64 KB EEPROM backup                                              | —    | 1.3  | 1.9  | ms            |       |
| $t_{\text{setram256k}}$                        | • 256 KB EEPROM backup                                             | —    | 4.5  | 5.5  | ms            |       |
| Byte-write to FlexRAM for EEPROM operation     |                                                                    |      |      |      |               |       |
| $t_{\text{eewr8bers}}$                         | Byte-write to erased FlexRAM location execution time               | —    | 175  | 260  | $\mu\text{s}$ | 3     |
| $t_{\text{eewr8b32k}}$                         | Byte-write to FlexRAM execution time:<br>• 32 KB EEPROM backup     | —    | 385  | 1800 | $\mu\text{s}$ |       |
| $t_{\text{eewr8b64k}}$                         | • 64 KB EEPROM backup                                              | —    | 475  | 2000 | $\mu\text{s}$ |       |
| $t_{\text{eewr8b128k}}$                        | • 128 KB EEPROM backup                                             | —    | 650  | 2400 | $\mu\text{s}$ |       |
| $t_{\text{eewr8b256k}}$                        | • 256 KB EEPROM backup                                             | —    | 1000 | 3200 | $\mu\text{s}$ |       |
| Word-write to FlexRAM for EEPROM operation     |                                                                    |      |      |      |               |       |
| $t_{\text{eewr16bers}}$                        | Word-write to erased FlexRAM location execution time               | —    | 175  | 260  | $\mu\text{s}$ |       |
| $t_{\text{eewr16b32k}}$                        | Word-write to FlexRAM execution time:<br>• 32 KB EEPROM backup     | —    | 385  | 1800 | $\mu\text{s}$ |       |
| $t_{\text{eewr16b64k}}$                        | • 64 KB EEPROM backup                                              | —    | 475  | 2000 | $\mu\text{s}$ |       |
| $t_{\text{eewr16b128k}}$                       | • 128 KB EEPROM backup                                             | —    | 650  | 2400 | $\mu\text{s}$ |       |
| $t_{\text{eewr16b256k}}$                       | • 256 KB EEPROM backup                                             | —    | 1000 | 3200 | $\mu\text{s}$ |       |
| Longword-write to FlexRAM for EEPROM operation |                                                                    |      |      |      |               |       |
| $t_{\text{eewr32bers}}$                        | Longword-write to erased FlexRAM location execution time           | —    | 360  | 540  | $\mu\text{s}$ |       |
| $t_{\text{eewr32b32k}}$                        | Longword-write to FlexRAM execution time:<br>• 32 KB EEPROM backup | —    | 630  | 2050 | $\mu\text{s}$ |       |
| $t_{\text{eewr32b64k}}$                        | • 64 KB EEPROM backup                                              | —    | 810  | 2250 | $\mu\text{s}$ |       |
| $t_{\text{eewr32b128k}}$                       | • 128 KB EEPROM backup                                             | —    | 1200 | 2675 | $\mu\text{s}$ |       |
| $t_{\text{eewr32b256k}}$                       | • 256 KB EEPROM backup                                             | —    | 1900 | 3500 | $\mu\text{s}$ |       |

## Peripheral operating requirements and behaviors

1. Assumes 25 MHz flash clock frequency.
2. Maximum times for erase parameters based on expectations at cycling end-of-life.
3. For byte-writes to an erased FlexRAM location, the aligned word containing the byte must be erased.

### 6.4.1.3 Flash high voltage current behaviors

**Table 22. Flash high voltage current behaviors**

| Symbol              | Description                                                           | Min. | Typ. | Max. | Unit |
|---------------------|-----------------------------------------------------------------------|------|------|------|------|
| I <sub>DD_PGM</sub> | Average current adder during high voltage flash programming operation | —    | 2.5  | 6.0  | mA   |
| I <sub>DD_ERS</sub> | Average current adder during high voltage flash erase operation       | —    | 1.5  | 4.0  | mA   |

### 6.4.1.4 Reliability specifications

**Table 23. NVM reliability specifications**

| Symbol                   | Description                                  | Min.   | Typ. <sup>1</sup> | Max. | Unit   | Notes |
|--------------------------|----------------------------------------------|--------|-------------------|------|--------|-------|
| Program Flash            |                                              |        |                   |      |        |       |
| t <sub>nvmretp10k</sub>  | Data retention after up to 10 K cycles       | 5      | 50                | —    | years  |       |
| t <sub>nvmretp1k</sub>   | Data retention after up to 1 K cycles        | 20     | 100               | —    | years  |       |
| n <sub>nvmcycp</sub>     | Cycling endurance                            | 10 K   | 50 K              | —    | cycles | 2     |
| Data Flash               |                                              |        |                   |      |        |       |
| t <sub>nvmretd10k</sub>  | Data retention after up to 10 K cycles       | 5      | 50                | —    | years  |       |
| t <sub>nvmretd1k</sub>   | Data retention after up to 1 K cycles        | 20     | 100               | —    | years  |       |
| n <sub>nvmcycd</sub>     | Cycling endurance                            | 10 K   | 50 K              | —    | cycles | 2     |
| FlexRAM as EEPROM        |                                              |        |                   |      |        |       |
| t <sub>nvmretee100</sub> | Data retention up to 100% of write endurance | 5      | 50                | —    | years  |       |
| t <sub>nvmretee10</sub>  | Data retention up to 10% of write endurance  | 20     | 100               | —    | years  |       |
| n <sub>nvmwree16</sub>   | Write endurance                              | 35 K   | 175 K             | —    | writes | 3     |
| n <sub>nvmwree128</sub>  | • EEPROM backup to FlexRAM ratio = 128       | 315 K  | 1.6 M             | —    | writes |       |
| n <sub>nvmwree512</sub>  | • EEPROM backup to FlexRAM ratio = 512       | 1.27 M | 6.4 M             | —    | writes |       |
| n <sub>nvmwree4k</sub>   | • EEPROM backup to FlexRAM ratio = 4096      | 10 M   | 50 M              | —    | writes |       |
| n <sub>nvmwree32k</sub>  | • EEPROM backup to FlexRAM ratio = 32,768    | 80 M   | 400 M             | —    | writes |       |

1. Typical data retention values are based on measured response accelerated at high temperature and derated to a constant 25°C use profile. Engineering Bulletin EB618 does not apply to this technology. Typical endurance defined in Engineering Bulletin EB619.
2. Cycling endurance represents number of program/erase cycles at -40°C ≤ T<sub>j</sub> ≤ 125°C.
3. Write endurance represents the number of writes to each FlexRAM location at -40°C ≤ T<sub>j</sub> ≤ 125°C influenced by the cycling endurance of the FlexNVM (same value as data flash) and the allocated EEPROM backup per subsystem. Minimum and typical values assume all byte-writes to FlexRAM.

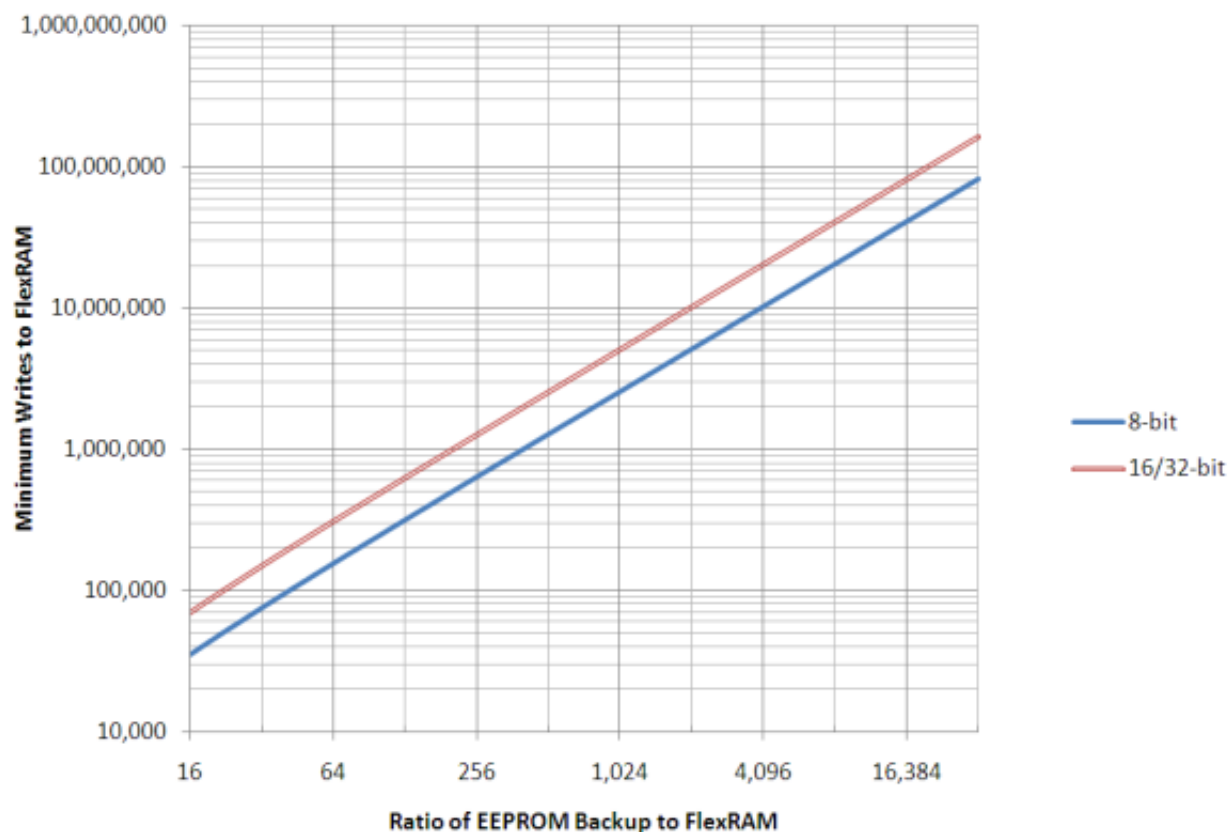


Figure 9. EEPROM backup writes to FlexRAM

## 6.4.2 EzPort switching specifications

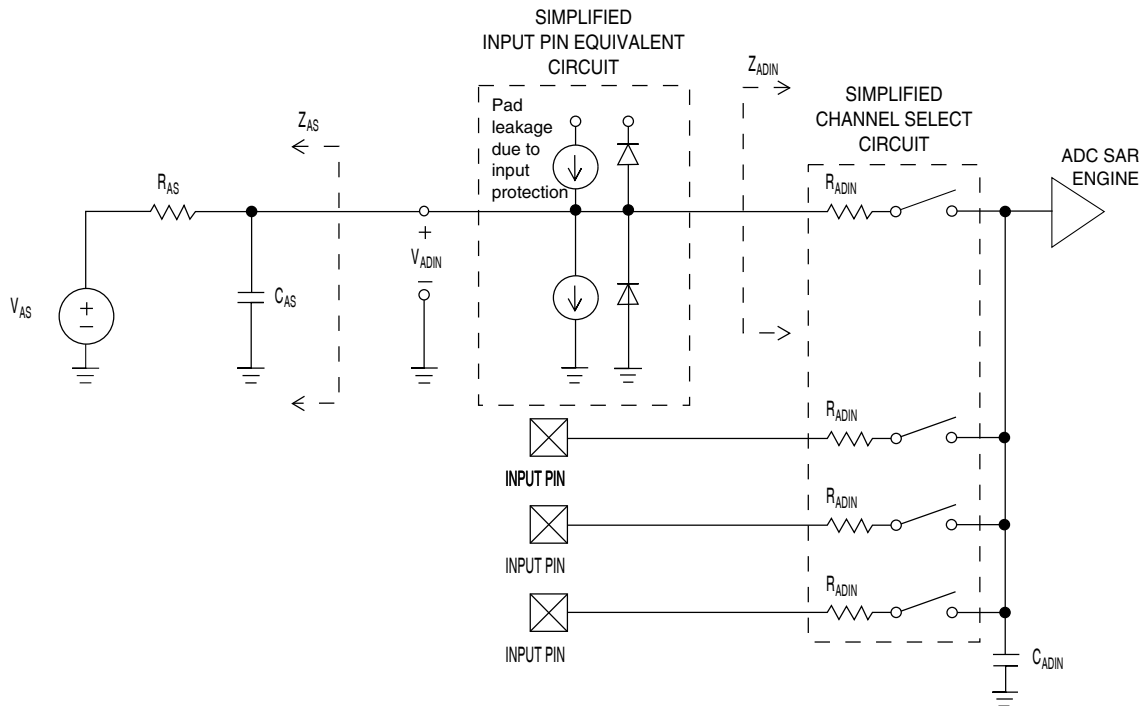
Table 24. EzPort switching specifications

| Num  | Description                                              | Min.                   | Max.        | Unit |
|------|----------------------------------------------------------|------------------------|-------------|------|
|      | Operating voltage                                        | 1.71                   | 3.6         | V    |
| EP1  | EZP_CK frequency of operation (all commands except READ) | —                      | $f_{SYS}/2$ | MHz  |
| EP1a | EZP_CK frequency of operation (READ command)             | —                      | $f_{SYS}/8$ | MHz  |
| EP2  | EZP_CS negation to next EZP_CS assertion                 | $2 \times t_{EZP\_CK}$ | —           | ns   |
| EP3  | EZP_CS input valid to EZP_CK high (setup)                | 5                      | —           | ns   |
| EP4  | EZP_CK high to EZP_CS input invalid (hold)               | 5                      | —           | ns   |
| EP5  | EZP_D input valid to EZP_CK high (setup)                 | 2                      | —           | ns   |
| EP6  | EZP_CK high to EZP_D input invalid (hold)                | 5                      | —           | ns   |
| EP7  | EZP_CK low to EZP_Q output valid                         | —                      | 16          | ns   |
| EP8  | EZP_CK low to EZP_Q output invalid (hold)                | 0                      | —           | ns   |
| EP9  | EZP_CS negation to EZP_Q tri-state                       | —                      | 12          | ns   |

**Table 27. 16-bit ADC operating conditions (continued)**

| Symbol     | Description         | Conditions                                                                                                 | Min.   | Typ. <sup>1</sup> | Max.    | Unit | Notes |
|------------|---------------------|------------------------------------------------------------------------------------------------------------|--------|-------------------|---------|------|-------|
| $C_{rate}$ | ADC conversion rate | 16-bit mode<br>No ADC hardware averaging<br><br>Continuous conversions enabled, subsequent conversion time | 37.037 | —                 | 461.467 | Ksps | 5     |

1. Typical values assume  $V_{DDA} = 3.0\text{ V}$ ,  $Temp = 25\text{ }^{\circ}\text{C}$ ,  $f_{ADCK} = 1.0\text{ MHz}$ , unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had  $< 8\text{ }\Omega$  analog source resistance. The  $R_{AS}/C_{AS}$  time constant should be kept to  $< 1\text{ ns}$ .
4. To use the maximum ADC conversion clock frequency,  $CFG2[ADHSC]$  must be set and  $CFG1[ADLPC]$  must be clear.
5. For guidelines and examples of conversion rate calculation, download the [ADC calculator tool](#).



**Figure 13. ADC input impedance equivalency diagram**

### 6.6.1.2 16-bit ADC electrical characteristics

**Table 28. 16-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ )**

| Symbol         | Description    | Conditions <sup>1</sup> | Min.  | Typ. <sup>2</sup> | Max. | Unit | Notes |
|----------------|----------------|-------------------------|-------|-------------------|------|------|-------|
| $I_{DDA\_ADC}$ | Supply current |                         | 0.215 | —                 | 1.7  | mA   | 3     |

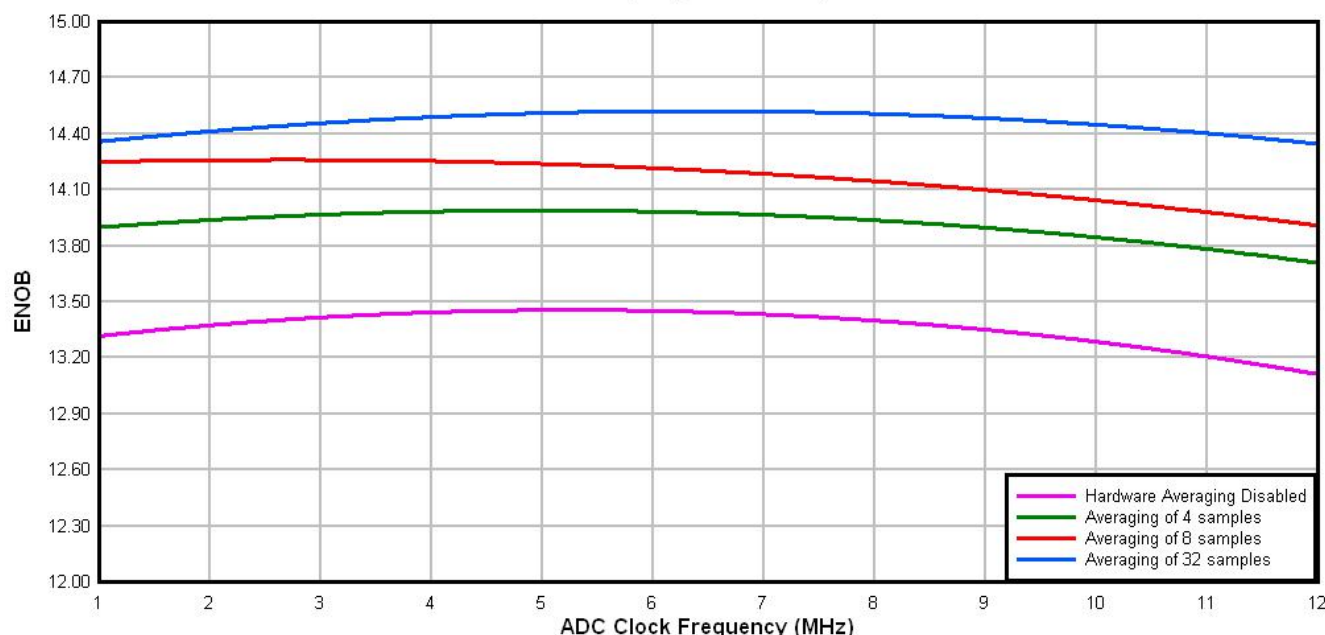
Table continues on the next page...

**Table 28. 16-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ ) (continued)**

| Symbol       | Description         | Conditions <sup>1</sup>                         | Min.                   | Typ. <sup>2</sup> | Max. | Unit  | Notes                                                                                        |
|--------------|---------------------|-------------------------------------------------|------------------------|-------------------|------|-------|----------------------------------------------------------------------------------------------|
| $E_{IL}$     | Input leakage error |                                                 | $I_{IN} \times R_{AS}$ |                   |      | mV    | $I_{IN}$ = leakage current<br><br>(refer to the MCU's voltage and current operating ratings) |
|              | Temp sensor slope   | Across the full temperature range of the device | 1.55                   | 1.62              | 1.69 | mV/°C |                                                                                              |
| $V_{TEMP25}$ | Temp sensor voltage | 25 °C                                           | 706                    | 716               | 726  | mV    |                                                                                              |

1. All accuracy numbers assume the ADC is calibrated with  $V_{REFH} = V_{DDA}$
2. Typical values assume  $V_{DDA} = 3.0$  V, Temp = 25 °C,  $f_{ADCK} = 2.0$  MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
3. The ADC supply current depends on the ADC conversion clock speed, conversion rate and ADC\_CFG1[ADLPC] (low power). For lowest power operation, ADC\_CFG1[ADLPC] must be set, the ADC\_CFG2[ADHSC] bit must be clear with 1 MHz ADC conversion clock speed.
4.  $1 \text{ LSB} = (V_{REFH} - V_{REFL})/2^N$
5. ADC conversion clock < 16 MHz, Max hardware averaging (AVGE = %1, AVGS = %11)
6. Input data is 100 Hz sine wave. ADC conversion clock < 12 MHz.
7. Input data is 1 kHz sine wave. ADC conversion clock < 12 MHz.

**Typical ADC 16-bit Differential ENOB vs ADC Clock**  
100Hz, 90% FS Sine Input



**Figure 14. Typical ENOB vs. ADC\_CLK for 16-bit differential mode**

**Table 34. Op-amp electrical specifications (continued)**

| Symbol       | Description                                                                                         | Min. | Typ.            | Max.       | Unit   |
|--------------|-----------------------------------------------------------------------------------------------------|------|-----------------|------------|--------|
| $I_{BIAS}$   | Typical input bias current across the following temp range (0–50°C)                                 | —    | ±500            | —          | pA     |
| $I_{BIAS}$   | Typical input bias current across the following temp range (-40–105°C)                              | —    | ±4              | —          | nA     |
| $V_{CML}$    | Input common mode voltage low                                                                       | 0    | —               | —          | V      |
| $V_{CMH}$    | Input common mode voltage high                                                                      | —    | —               | VDD        | V      |
| $R_{IN}$     | Input resistance                                                                                    | —    | 500             | —          | MΩ     |
| $C_{IN}$     | Input capacitance                                                                                   | —    | 17 <sup>1</sup> | —          | pF     |
| $ X_{IN} $   | AC input impedance ( $f_{IN}=100\text{kHz}$ )                                                       | —    | 50              | —          | MΩ     |
| CMRR         | Input common mode rejection ratio                                                                   | 60   | —               | —          | dB     |
| PSRR         | Power supply rejection ratio                                                                        | 60   | —               | —          | dB     |
| SR           | Slew rate ( $\Delta V_{IN}=500\text{mV}$ ), low-power mode                                          | 0.1  | —               | —          | V/μs   |
| SR           | Slew rate ( $\Delta V_{IN}=500\text{mV}$ ), high-speed mode                                         | 1.5  | 4               | —          | V/μs   |
| GBW          | Unity gain bandwidth, low-power mode                                                                | 0.15 | —               | —          | MHz    |
| GBW          | Unity gain bandwidth, high-speed mode                                                               | 1    | —               | —          | MHz    |
| $A_V$        | DC open-loop voltage gain                                                                           | 80   | 90              | —          | dB     |
| CL(max)      | Load capacitance driving capability                                                                 | —    | 100             | —          | pF     |
| $R_{OUT}$    | Output resistance @ 100 kHz, high speed mode                                                        | —    | 1500            | —          | Ω      |
| $V_{OUT}$    | Output voltage range                                                                                | 0.12 | —               | VDD - 0.12 | V      |
| $I_{OUT}$    | Output load current                                                                                 | —    | ±0.5            | —          | mA     |
| GM           | Gain margin                                                                                         | —    | 20              | —          | dB     |
| PM           | Phase margin                                                                                        | 45   | 56              | —          | deg    |
| $T_{settle}$ | Settling time <sup>2</sup> (Buffer mode, low-power mode) ( $T_o < 0.1\%$ , $V_{in}=1.65\text{V}$ )  | —    | 5.7             | —          | μs     |
| $T_{settle}$ | Settling time <sup>2</sup> (Buffer mode, high-speed mode) ( $T_o < 0.1\%$ , $V_{in}=1.65\text{V}$ ) | —    | 3.0             | —          | μs     |
| $V_n$        | Voltage noise density (noise floor) 1kHz                                                            | —    | 350             | —          | nV/√Hz |
| $V_n$        | Voltage noise density (noise floor) 10kHz                                                           | —    | 90              | —          | nV/√Hz |

1. The input capacitance is dependant on the package type used.
2. Settling time is measured from the time the Op-amp is enabled until the output settles to within 0.1% of final value. This time includes Op-amp startup time, output slew, and settle time.

## 6.6.5 Transimpedance amplifier electrical specifications — full range

**Table 35. TRIAMP full range operating requirements**

| Symbol    | Description             | Min. | Max.          | Unit | Notes |
|-----------|-------------------------|------|---------------|------|-------|
| $V_{DDA}$ | Supply voltage          | 1.71 | 3.6           | V    |       |
| $V_{IN}$  | Input voltage range     | -0.1 | $V_{DDA}-1.4$ | V    |       |
| $C_L$     | Output load capacitance | —    | 100           | pf   |       |

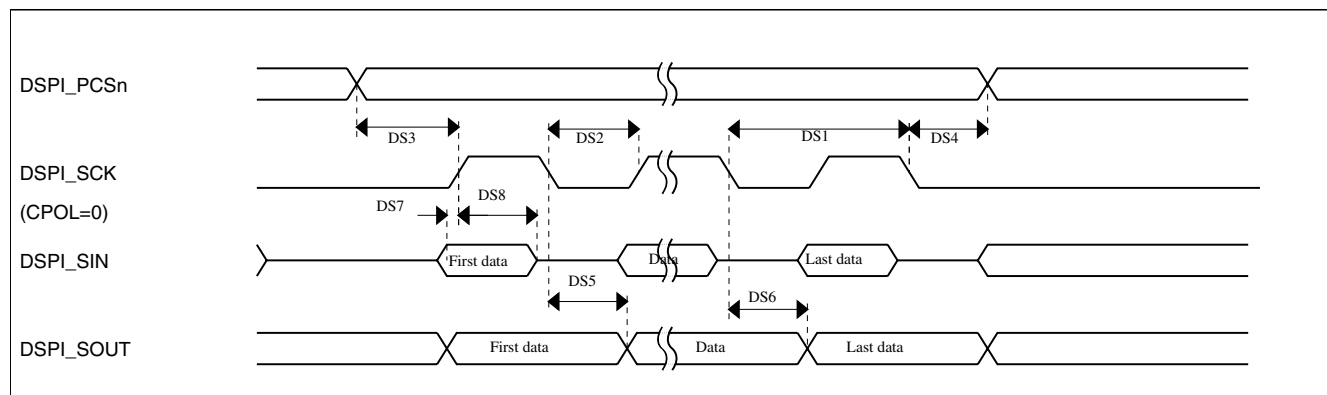
## 6.8.5 DSPI switching specifications (limited voltage range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provide DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

**Table 47. Master mode DSPI timing (limited voltage range)**

| Num | Description                         | Min.                     | Max.              | Unit | Notes |
|-----|-------------------------------------|--------------------------|-------------------|------|-------|
|     | Operating voltage                   | 2.7                      | 3.6               | V    |       |
|     | Frequency of operation              | —                        | 25                | MHz  |       |
| DS1 | DSPI_SCK output cycle time          | $2 \times t_{BUS}$       | —                 | ns   |       |
| DS2 | DSPI_SCK output high/low time       | $(t_{SCK}/2) - 2$        | $(t_{SCK}/2) + 2$ | ns   |       |
| DS3 | DSPI_PCSn valid to DSPI_SCK delay   | $(t_{BUS} \times 2) - 2$ | —                 | ns   | 1     |
| DS4 | DSPI_SCK to DSPI_PCSn invalid delay | $(t_{BUS} \times 2) - 2$ | —                 | ns   | 2     |
| DS5 | DSPI_SCK to DSPI_SOUT valid         | —                        | 8                 | ns   |       |
| DS6 | DSPI_SCK to DSPI_SOUT invalid       | 0                        | —                 | ns   |       |
| DS7 | DSPI_SIN to DSPI_SCK input setup    | 14                       | —                 | ns   |       |
| DS8 | DSPI_SCK to DSPI_SIN input hold     | 0                        | —                 | ns   |       |

1. The delay is programmable in SPIx\_CTARn[PSSCK] and SPIx\_CTARn[CSSCK].
2. The delay is programmable in SPIx\_CTARn[PASC] and SPIx\_CTARn[ASC].



**Figure 22. DSPI classic SPI timing — master mode**

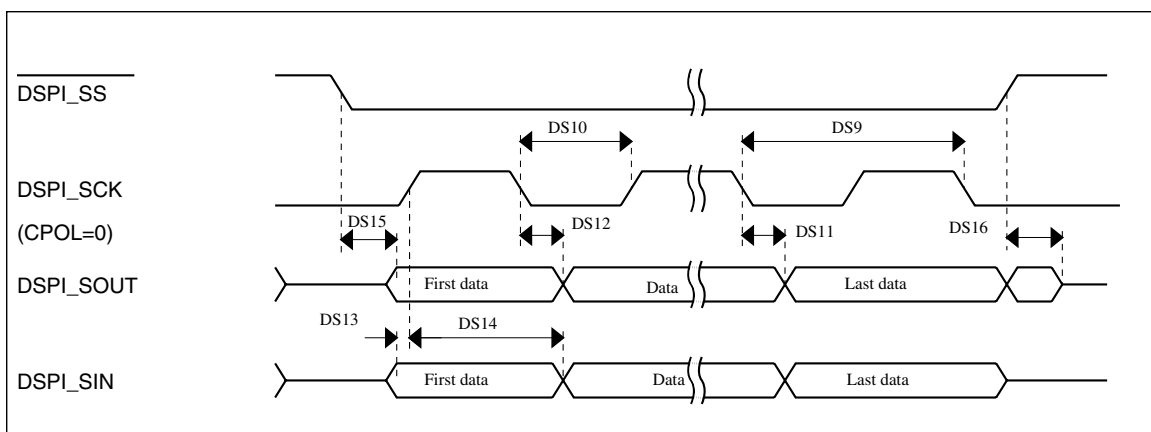
**Table 48. Slave mode DSPI timing (limited voltage range)**

| Num | Description               | Min.               | Max. | Unit |
|-----|---------------------------|--------------------|------|------|
|     | Operating voltage         | 2.7                | 3.6  | V    |
|     | Frequency of operation    |                    | 12.5 | MHz  |
| DS9 | DSPI_SCK input cycle time | $4 \times t_{BUS}$ | —    | ns   |

Table continues on the next page...

**Table 48. Slave mode DSPI timing (limited voltage range) (continued)**

| Num  | Description                              | Min.                     | Max.                     | Unit    |
|------|------------------------------------------|--------------------------|--------------------------|---------|
| DS10 | DSPI_SCK input high/low time             | $(t_{\text{SCK}}/2) - 2$ | $(t_{\text{SCK}}/2) + 2$ | ns      |
| DS11 | DSPI_SCK to DSPI_SOUT valid              | —                        | 20                       | ns      |
| DS12 | DSPI_SCK to DSPI_SOUT invalid            | 0                        | —                        | ns      |
| DS13 | DSPI_SIN to DSPI_SCK input setup         | 2                        | —                        | ns      |
| DS14 | DSPI_SCK to DSPI_SIN input hold          | 7                        | —                        | ns      |
| DS15 | DSPI_SS active to DSPI_SOUT driven       | —                        | 14                       | ns </td |
| DS16 | DSPI_SS inactive to DSPI_SOUT not driven | —                        | 14                       | ns      |


**Figure 23. DSPI classic SPI timing — slave mode**

### 6.8.6 DSPI switching specifications (full voltage range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provides DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

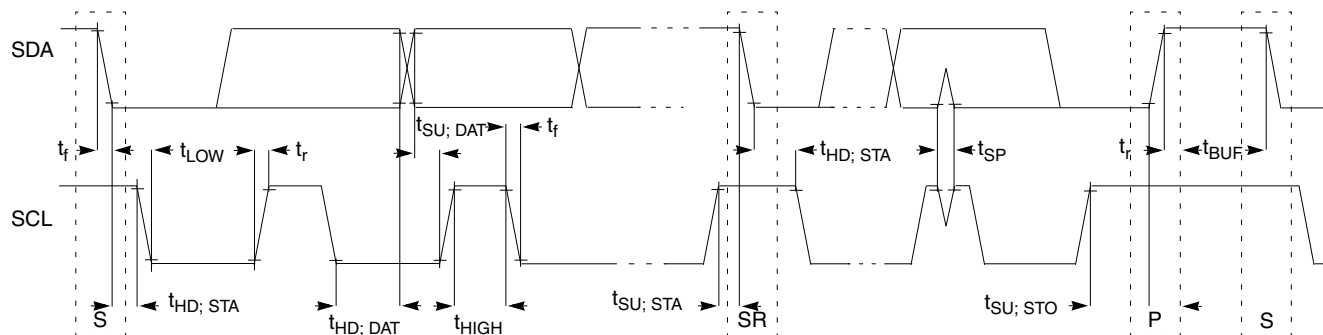
**Table 49. Master mode DSPI timing (full voltage range)**

| Num | Description                       | Min.                            | Max.                     | Unit | Notes |
|-----|-----------------------------------|---------------------------------|--------------------------|------|-------|
|     | Operating voltage                 | 1.71                            | 3.6                      | V    | 1     |
|     | Frequency of operation            | —                               | 12.5                     | MHz  |       |
| DS1 | DSPI_SCK output cycle time        | $4 \times t_{\text{BUS}}$       | —                        | ns   |       |
| DS2 | DSPI_SCK output high/low time     | $(t_{\text{SCK}}/2) - 4$        | $(t_{\text{SCK}}/2) + 4$ | ns   |       |
| DS3 | DSPI_PCSn valid to DSPI_SCK delay | $(t_{\text{BUS}} \times 2) - 4$ | —                        | ns   | 2     |

Table continues on the next page...



6.  $C_b$  = total capacitance of the one bus line in pF.



**Figure 26. Timing definition for fast and standard mode devices on the I²C bus**

## 6.8.8 UART switching specifications

See [General switching specifications](#).

## 6.8.9 SDHC specifications

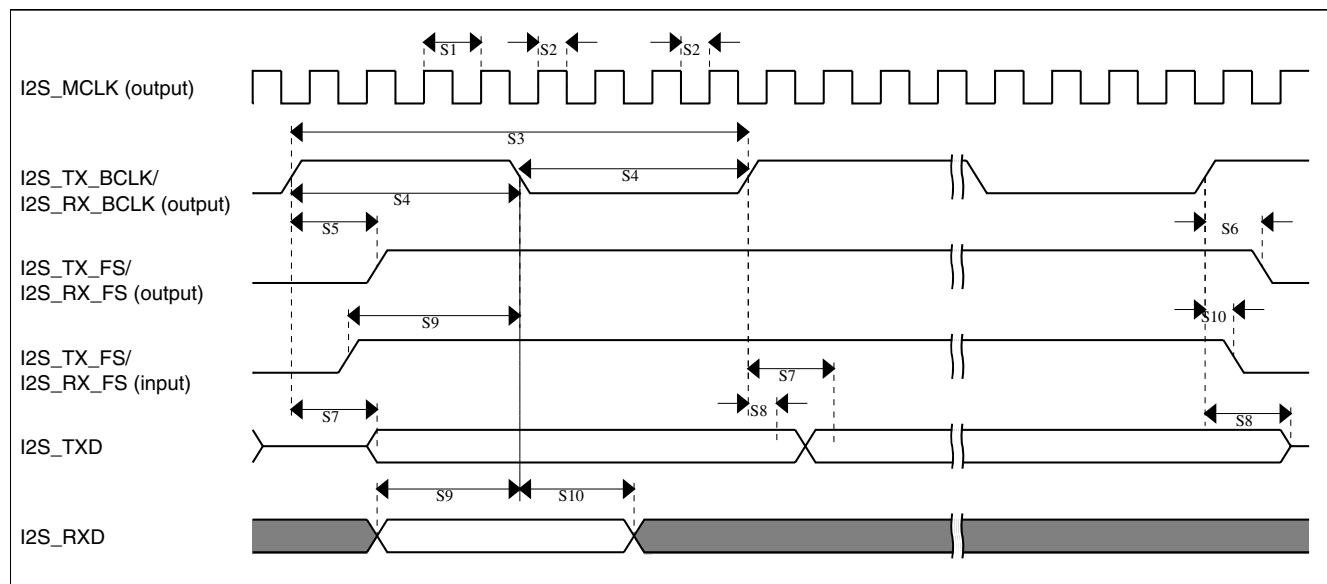
The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

**Table 52. SDHC switching specifications**

| Num | Symbol           | Description                                                                 | Min. | Max.  | Unit |
|-----|------------------|-----------------------------------------------------------------------------|------|-------|------|
|     |                  | Operating voltage                                                           | 1.71 | 3.6   | V    |
|     |                  | <b>Card input clock</b>                                                     |      |       |      |
| SD1 | fpp              | Clock frequency (low speed)                                                 | 0    | 400   | kHz  |
|     | fpp              | Clock frequency (SD\SDIO full speed\high speed)                             | 0    | 25\50 | MHz  |
|     | fpp              | Clock frequency (MMC full speed\high speed)                                 | 0    | 20\50 | MHz  |
|     | f <sub>OD</sub>  | Clock frequency (identification mode)                                       | 0    | 400   | kHz  |
| SD2 | t <sub>WL</sub>  | Clock low time                                                              | 7    | —     | ns   |
| SD3 | t <sub>WH</sub>  | Clock high time                                                             | 7    | —     | ns   |
| SD4 | t <sub>TLH</sub> | Clock rise time                                                             | —    | 3     | ns   |
| SD5 | t <sub>THL</sub> | Clock fall time                                                             | —    | 3     | ns   |
|     |                  | <b>SDHC output / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)</b> |      |       |      |
| SD6 | t <sub>OD</sub>  | SDHC output delay (output valid)                                            | -5   | 8.3   | ns   |
|     |                  | <b>SDHC input / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)</b>  |      |       |      |
| SD7 | t <sub>ISU</sub> | SDHC input setup time                                                       | 5    | —     | ns   |
| SD8 | t <sub>IH</sub>  | SDHC input hold time                                                        | 0    | —     | ns   |

**Table 53. I2S/SAI master mode timing in Normal Run, Wait and Stop modes (limited voltage range) (continued)**

| Num. | Characteristic                                                    | Min. | Max. | Unit |
|------|-------------------------------------------------------------------|------|------|------|
| S6   | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/<br>I2S_RX_FS output invalid | 0    | —    | ns   |
| S7   | I2S_TX_BCLK to I2S_TXD valid                                      | —    | 15   | ns   |
| S8   | I2S_TX_BCLK to I2S_TXD invalid                                    | 0    | —    | ns   |
| S9   | I2S_RXD/I2S_RX_FS input setup before<br>I2S_RX_BCLK               | 15   | —    | ns   |
| S10  | I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK                    | 0    | —    | ns   |



**Figure 28. I2S/SAI timing — master modes**

**Table 54. I2S/SAI slave mode timing in Normal Run, Wait and Stop modes (limited voltage range)**

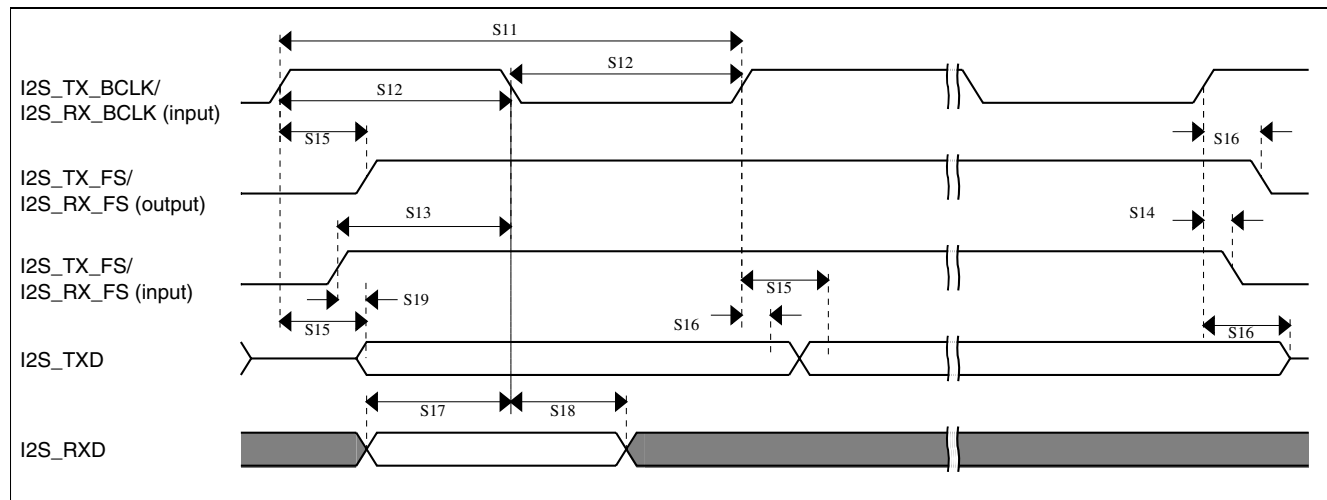
| Num. | Characteristic                                                    | Min. | Max. | Unit        |
|------|-------------------------------------------------------------------|------|------|-------------|
|      | Operating voltage                                                 | 2.7  | 3.6  | V           |
| S11  | I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)                        | 80   | —    | ns          |
| S12  | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low<br>(input)           | 45%  | 55%  | MCLK period |
| S13  | I2S_TX_FS/I2S_RX_FS input setup before<br>I2S_TX_BCLK/I2S_RX_BCLK | 4.5  | —    | ns          |
| S14  | I2S_TX_FS/I2S_RX_FS input hold after<br>I2S_TX_BCLK/I2S_RX_BCLK   | 2    | —    | ns          |
| S15  | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid                     | —    | 21   | ns          |
|      | • Multiple SAI Synchronous mode                                   | —    | 15   |             |
|      | • All other modes                                                 | —    | 15   |             |

Table continues on the next page...

**Table 54. I2S/SAI slave mode timing in Normal Run, Wait and Stop modes (limited voltage range) (continued)**

| Num. | Characteristic                                                 | Min. | Max. | Unit |
|------|----------------------------------------------------------------|------|------|------|
| S16  | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid                | 0    | —    | ns   |
| S17  | I2S_RXD setup before I2S_RX_BCLK                               | 4.5  | —    | ns   |
| S18  | I2S_RXD hold after I2S_RX_BCLK                                 | 2    | —    | ns   |
| S19  | I2S_TX_FS input assertion to I2S_TXD output valid <sup>1</sup> | —    | 25   | ns   |

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear



**Figure 29. I2S/SAI timing — slave modes**

### 6.8.10.2 Normal Run, Wait and Stop mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in Normal Run, Wait and Stop modes.

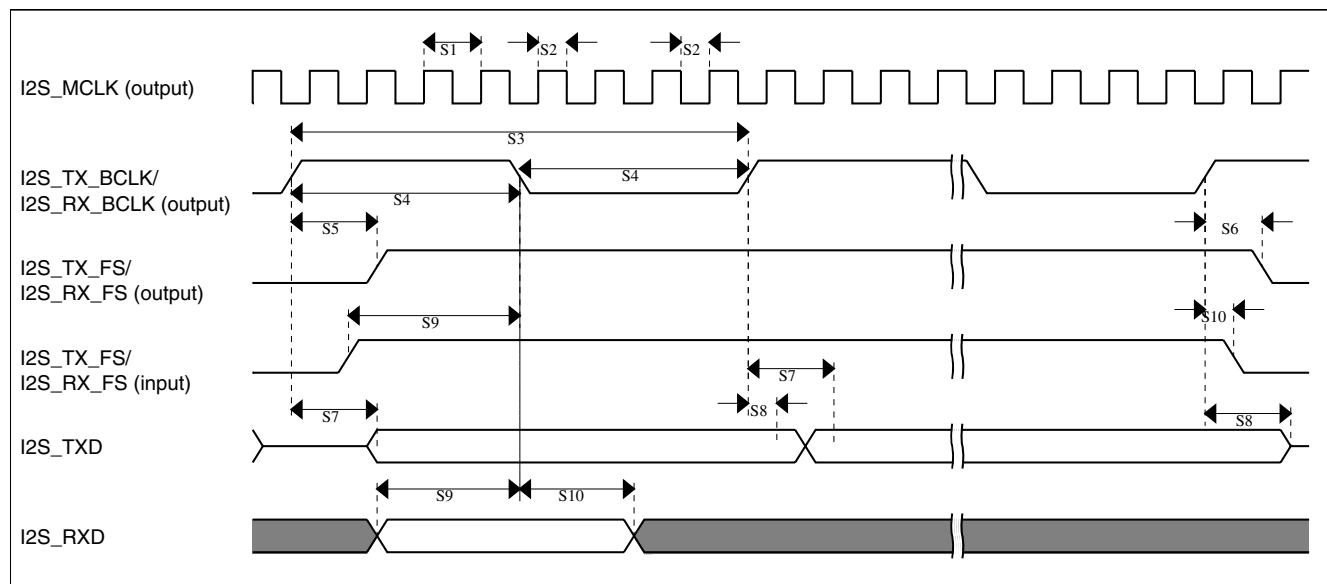
**Table 55. I2S/SAI master mode timing in Normal Run, Wait and Stop modes (full voltage range)**

| Num. | Characteristic                                                | Min. | Max. | Unit        |
|------|---------------------------------------------------------------|------|------|-------------|
|      | Operating voltage                                             | 1.71 | 3.6  | V           |
| S1   | I2S_MCLK cycle time                                           | 40   | —    | ns          |
| S2   | I2S_MCLK pulse width high/low                                 | 45%  | 55%  | MCLK period |
| S3   | I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)                   | 80   | —    | ns          |
| S4   | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low                  | 45%  | 55%  | BCLK period |
| S5   | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/I2S_RX_FS output valid   | —    | 15   | ns          |
| S6   | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/I2S_RX_FS output invalid | -1.0 | —    | ns          |

Table continues on the next page...

**Table 57. I2S/SAI master mode timing in VLPR, VLPW, and VLPS modes (full voltage range) (continued)**

| Num. | Characteristic                                   | Min. | Max. | Unit |
|------|--------------------------------------------------|------|------|------|
| S8   | I2S_TX_BCLK to I2S_TXD invalid                   | 0    | —    | ns   |
| S9   | I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK | 45   | —    | ns   |
| S10  | I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK   | 0    | —    | ns   |



**Figure 32. I2S/SAI timing — master modes**

**Table 58. I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range)**

| Num. | Characteristic                                                 | Min. | Max. | Unit        |
|------|----------------------------------------------------------------|------|------|-------------|
|      | Operating voltage                                              | 1.71 | 3.6  | V           |
| S11  | I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)                     | 250  | —    | ns          |
| S12  | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)           | 45%  | 55%  | MCLK period |
| S13  | I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK | 30   | —    | ns          |
| S14  | I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK   | 3    | —    | ns          |
| S15  | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid                  | —    | 63   | ns          |
| S16  | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid                | 0    | —    | ns          |
| S17  | I2S_RXD setup before I2S_RX_BCLK                               | 30   | —    | ns          |
| S18  | I2S_RXD hold after I2S_RX_BCLK                                 | 2    | —    | ns          |
| S19  | I2S_TX_FS input assertion to I2S_TXD output valid <sup>1</sup> | —    | 72   | ns          |

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

## Pinout

| 144<br>LQFP | 144<br>MAP<br>BGA | Pin Name          | Default               | ALT0                  | ALT1              | ALT2      | ALT3                                | ALT4            | ALT5    | ALT6      | ALT7    | EzPort |
|-------------|-------------------|-------------------|-----------------------|-----------------------|-------------------|-----------|-------------------------------------|-----------------|---------|-----------|---------|--------|
| 134         | A3                | PTD5              | LCD_P45/<br>ADC0_SE6b | LCD_P45/<br>ADC0_SE6b | PTD5              | SPI0_PCS2 | UART0_CTS_<br>b/<br>UART0_COL_<br>b | FTM0_CH5        |         | EWM_OUT_b | LCD_P45 |        |
| 135         | A2                | PTD6/<br>LLWU_P15 | LCD_P46/<br>ADC0_SE7b | LCD_P46/<br>ADC0_SE7b | PTD6/<br>LLWU_P15 | SPI0_PCS3 | UART0_RX                            | FTM0_CH6        |         | FTM0_FLT0 | LCD_P46 |        |
| 136         | M10               | VSS               | VSS                   | VSS                   |                   |           |                                     |                 |         |           |         |        |
| 137         | F8                | VDD               | VDD                   | VDD                   |                   |           |                                     |                 |         |           |         |        |
| 138         | A1                | PTD7              | LCD_P47               | LCD_P47               | PTD7              | CMT_IRO   | UART0_TX                            | FTM0_CH7        |         | FTM0_FLT1 | LCD_P47 |        |
| 139         | B3                | PTD10             | DISABLED              |                       | PTD10             |           | UART5_RTS_<br>b                     |                 | FB_AD9  |           |         |        |
| 140         | B2                | PTD11             | DISABLED              |                       | PTD11             | SPI2_PCS0 | UART5_CTS_<br>b                     | SDHC0_<br>CLKIN | FB_AD8  |           |         |        |
| 141         | B1                | PTD12             | DISABLED              |                       | PTD12             | SPI2_SCK  |                                     | SDHC0_D4        | FB_AD7  |           |         |        |
| 142         | C3                | PTD13             | DISABLED              |                       | PTD13             | SPI2_SOUT |                                     | SDHC0_D5        | FB_AD6  |           |         |        |
| 143         | C2                | PTD14             | DISABLED              |                       | PTD14             | SPI2_SIN  |                                     | SDHC0_D6        | FB_AD5  |           |         |        |
| 144         | C1                | PTD15             | DISABLED              |                       | PTD15             | SPI2_PCS1 |                                     | SDHC0_D7        | FB_RW_b |           |         |        |

## 8.2 K53 pinouts

The figure below shows the pinout diagram for the devices supported by this document. Many signals may be multiplexed onto a single pin. To determine what signals can be used on which pin, see the previous section.